Vishay Semiconductors

High Performance Schottky Rectifier, 1.0 A



www.vishay.com



SMB (DO-214AA)

| PRIMARY CHARACTERISTICS | | | | |
|----------------------------------|-----------------|--|--|--|
| I _{F(AV)} | 1.0 A | | | |
| V _R | 30 V | | | |
| V _F at I _F | 0.420 V | | | |
| I _{RM} max. | 15 mA at 125 °C | | | |
| T _J max. | 150 °C | | | |
| E _{AS} | 3.0 mJ | | | |
| Package | SMB (DO-214AA) | | | |
| Circuit configuration | Single | | | |

FEATURES

- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

The VS-10BQ030HM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | |
|-----------------------------------|---|-------------|-------|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | |
| I _{F(AV)} | Rectangular waveform | 1.0 | A | |
| V _{RRM} | | 30 | V | |
| I _{FSM} | t _p = 5 ms sine | 430 | А | |
| V _F | 1.0 A _{pk} , T _J = 125 °C | 0.30 | V | |
| TJ | Range | -55 to +150 | °C | |

| VOLTAGE RATINGS | | | | |
|--------------------------------------|------------------|---------------|-------|--|
| PARAMETER | SYMBOL | VS-10BQ030HM3 | UNITS | |
| Maximum DC reverse voltage | V _R | - 30 | V | |
| Maximum working peak reverse voltage | V _{RWM} | 30 | v | |

| ABSOLUTE MAXIMUM RATINGS | | | | | |
|--|--------------------|---|--|--------|-------|
| PARAMETER | SYMBOL | TEST CONDI | TIONS | VALUES | UNITS |
| Maximum average forward current | I _{F(AV)} | $I_{F(AV)}$ 50 % duty cycle at T_L = 106 °C, rectangular waveform | | 1.0 | |
| Maximum peak one cycle | | 5 µs sine or 3 µs rect. pulse | Following any rated | 430 | А |
| non-repetitive surge current See fig. 6 | I _{FSM} | 10 ms sine or 6 ms rect. pulse | load condition and with rated V _{RRM} applied | 90 | |
| Non-repetitive avalanche energy | E _{AS} | $T_J = 25 \text{ °C}, I_{AS} = 1 \text{ A}, L = 6 \text{ mH}$ 3.0 mJ | | mJ | |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical 1.0 | | А | |

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COMPLIANT

HALOGEN

FREE



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| ELECTRICAL SPECIFICATIONS | | | | | |
|---------------------------------|--------------------------------|--|---------------------------------------|--------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS |
| | | 1 A | T _J = 25 °C | 0.420 | V |
| Maximum famuard valtage drap | V (1) | 2 A | | 0.470 | |
| Maximum forward voltage drop | V _{FM} ⁽¹⁾ | 1 A | T _J = 125 °C | 0.300 | |
| | | 2 A | | 0.370 | |
| Maximum reverse leakage current | I _{RM} ⁽¹⁾ | T _J = 25 °C | V _R = Rated V _R | 0.5 | |
| | | T _J = 100 °C | | 5.0 | mA |
| | | T _J = 125 °C | | 15 | |
| Maximum junction capacitance | CT | $V_{\rm R}$ = 5 $V_{\rm DC}$ (test signal range 100 kHz to 1 MHz), 25 °C | | 200 | pF |
| Typical series inductance | L _S | Measured lead to lead 5 mm from package body | | 2.0 | nH |
| Maximum voltage rate of change | dV/dt | Rated V _R 10 000 V | | V/µs | |

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 $\,\%$

| THERMAL - MECHANICAL SPECIFICATIONS | | | | |
|---|--|---------------------------|-------------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum junction and storage temperature range | T _J ⁽¹⁾ , T _{Stg} | | -55 to +150 | °C |
| Maximum thermal resistance, junction to lead | R _{thJL} ⁽²⁾ | DC operation | 25 | °C/W |
| Maximum thermal resistance, junction to ambient | R _{thJA} | | 80 | 0/10 |
| Approximate weight | | | 0.10 | g |
| | | | 0.003 | OZ. |
| Marking device | | Case style SMB (DO-214AA) | 1 | E |

Notes

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink (1)

⁽²⁾ Mounted 1" square PCB

2



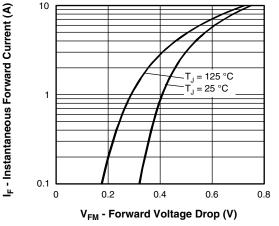


Fig. 1 - Maximum Forward Voltage Drop Characteristics

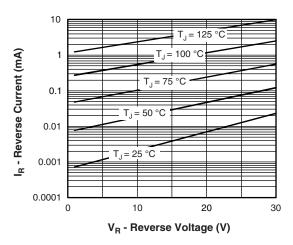


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

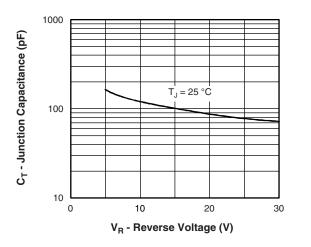


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$



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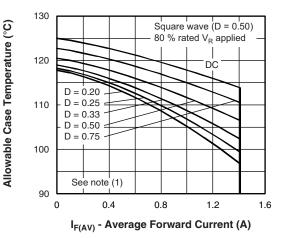


Fig. 4 - Maximum Average Forward Current vs. Allowable Lead Temperature

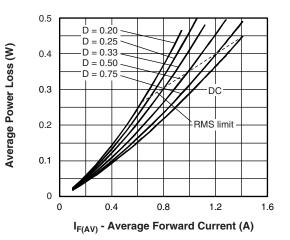


Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current

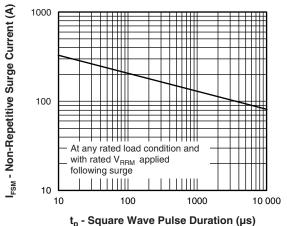


Fig. 6 - Maximum Peak Surge Forward Current vs.Pulse Duration

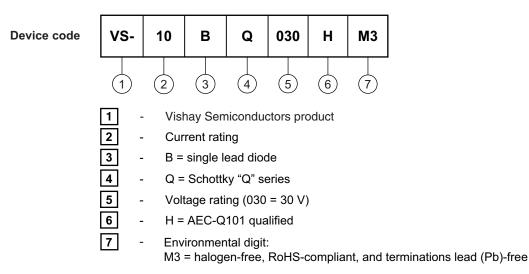
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ORDERING INFORMATION TABLE



| ORDERING INFORMATION (Example) | | | | | |
|--------------------------------|---|------|------------------------------------|--|--|
| PREFERRED P/N | PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION | | | | |
| VS-10BQ030HM3/5BT | 5BT | 3200 | 13" diameter plastic tape and reel | | |

| LINKS TO RELATED DOCUMENTS | | | |
|----------------------------|--------------------------|--|--|
| Dimensions | www.vishay.com/doc?95401 | | |
| Part marking information | www.vishay.com/doc?95403 | | |
| Packaging information | www.vishay.com/doc?95404 | | |

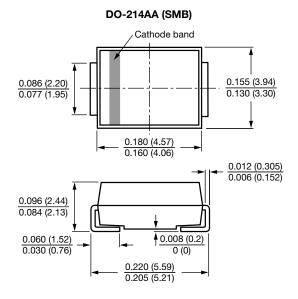


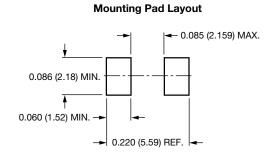
Outline Dimensions

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SMB

DIMENSIONS in inches (millimeters)







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